

# Development of a (Nb,Ti)<sub>3</sub>Sn multifilamentary wire with ZrO<sub>2</sub> APCs for high J<sub>c</sub>, high B<sub>c2</sub>, and low AC loss

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## Introduction

Nb<sub>3</sub>Sn performance improvement is needed for projects like the Future Circular Collider (FCC)

- Maximize J<sub>c</sub> at 16 T
- Maximize pinning force F<sub>p</sub> at high B

Refinement of grain size increases F<sub>p,max</sub>

- Add ZrO<sub>2</sub> particles to prevent grain coarsening during heat treatment [1]

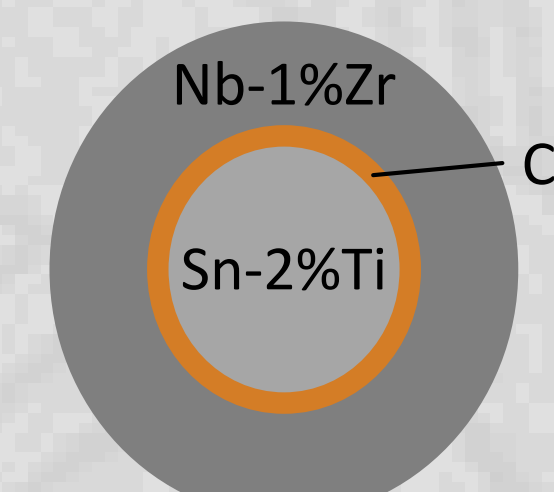
Next step is to produce a Ti-doped ternary wire to increase B<sub>c2</sub>

## Externally-Oxidized Subelement

We started with a proof-of-concept ternary strand consisting of a Cu-Sn-Ti rod inside a Nb-1%Zr tube. The wires were heat treated in a vacuum-sealed quartz tube containing varying amounts of CuO pellets.

Observations:

- Grain refinement to ~50 nm
- Ti incorporation in Nb<sub>3</sub>Sn layer
- Improvement of J<sub>c</sub> (calculated from PPMS M-H curve)



## Initial Multifilament Development

Trying out several designs:

- T3763: ternary hybrid wire
  - Inner ring of filaments contain Sn/SnO<sub>2</sub> powder
  - Remainder contain Sn-2%Ti rods
- T3761: Densely packed Sn/SnO<sub>2</sub> powder in Cu tube in Nb-1%Zr tube
- T3775: Another externally oxidized subelement containing 6%Ti
- Additional wire architectures are currently in production

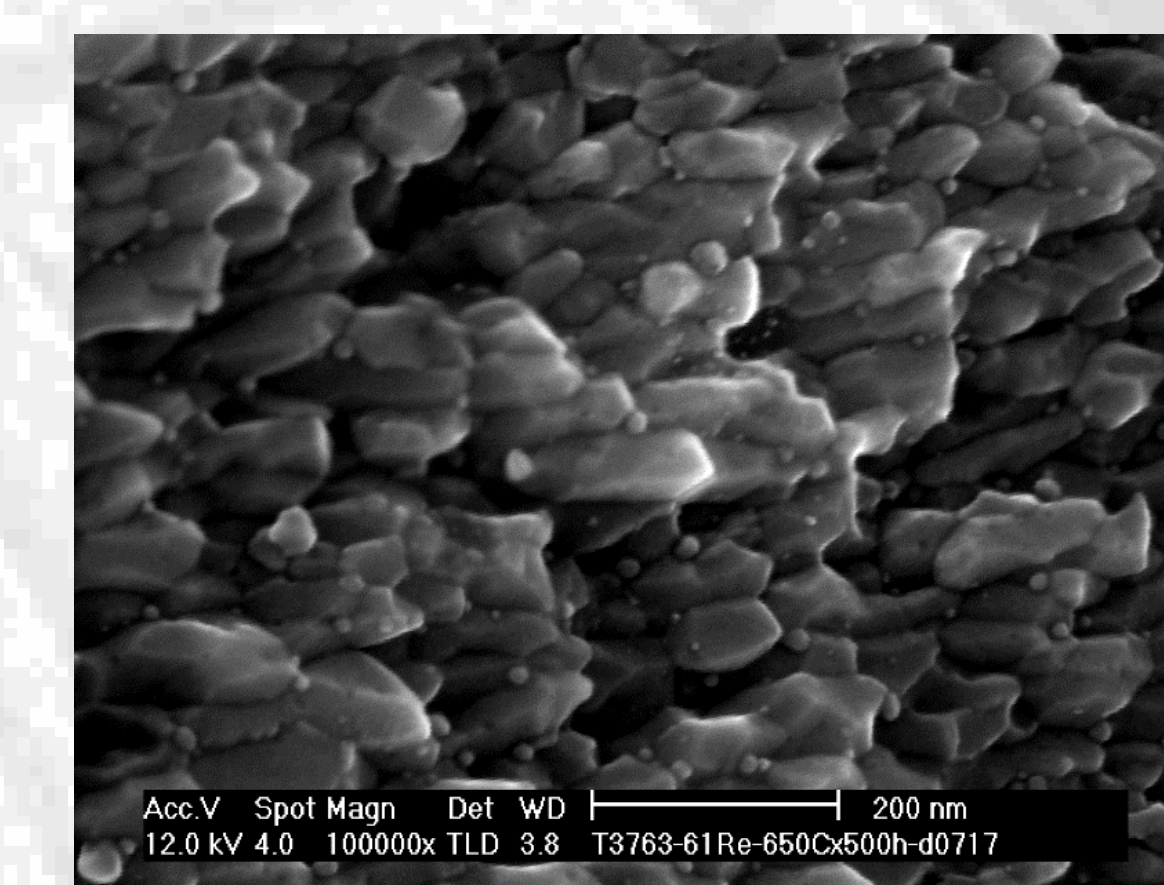
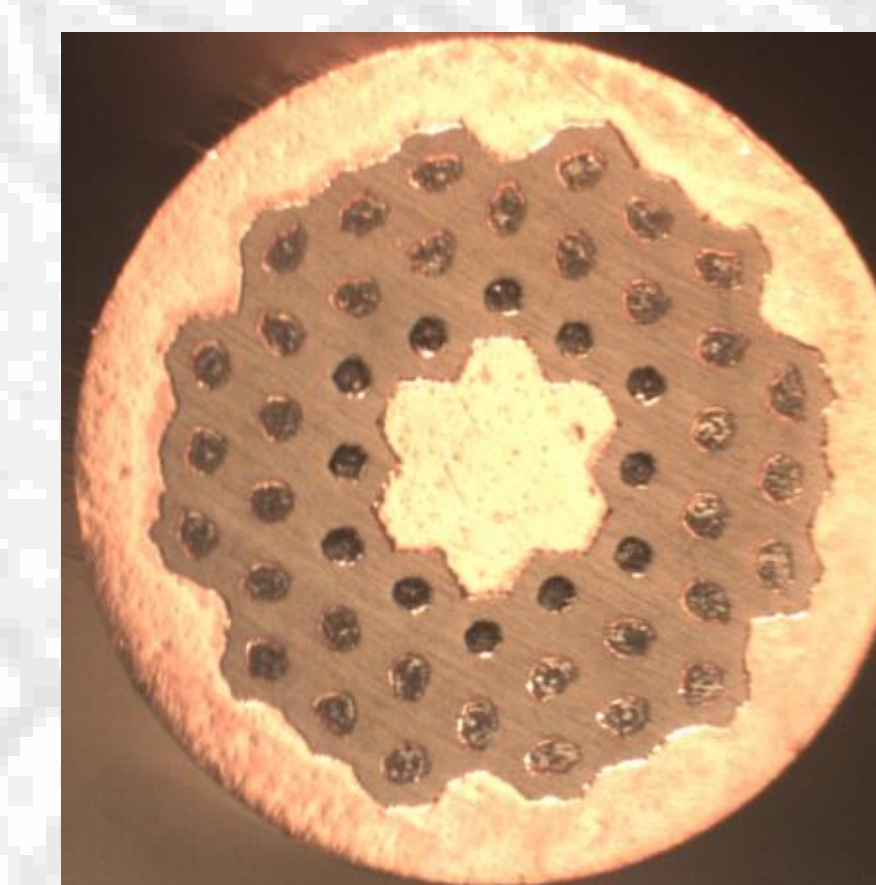


Table 1. Current state of Nb<sub>3</sub>Sn strands from various production routes

	Internal Sn, RRP	Tube	ITER	PIT	Bronze
12 T J <sub>c</sub> , A/mm <sup>2</sup>	2500-3000	2000-2500	1000-1200	2000-2500	600-800
Stability	Low	medium	high	medium	high
Loss	High	medium	low	medium	low

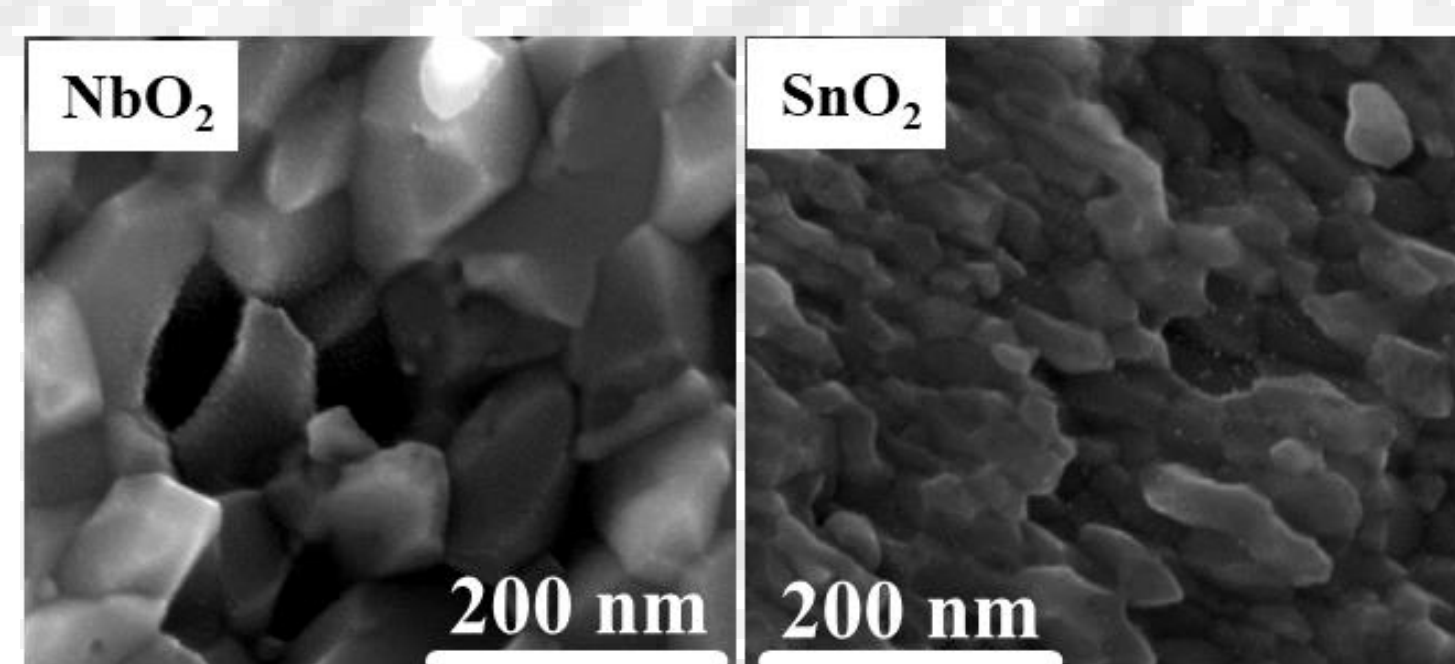
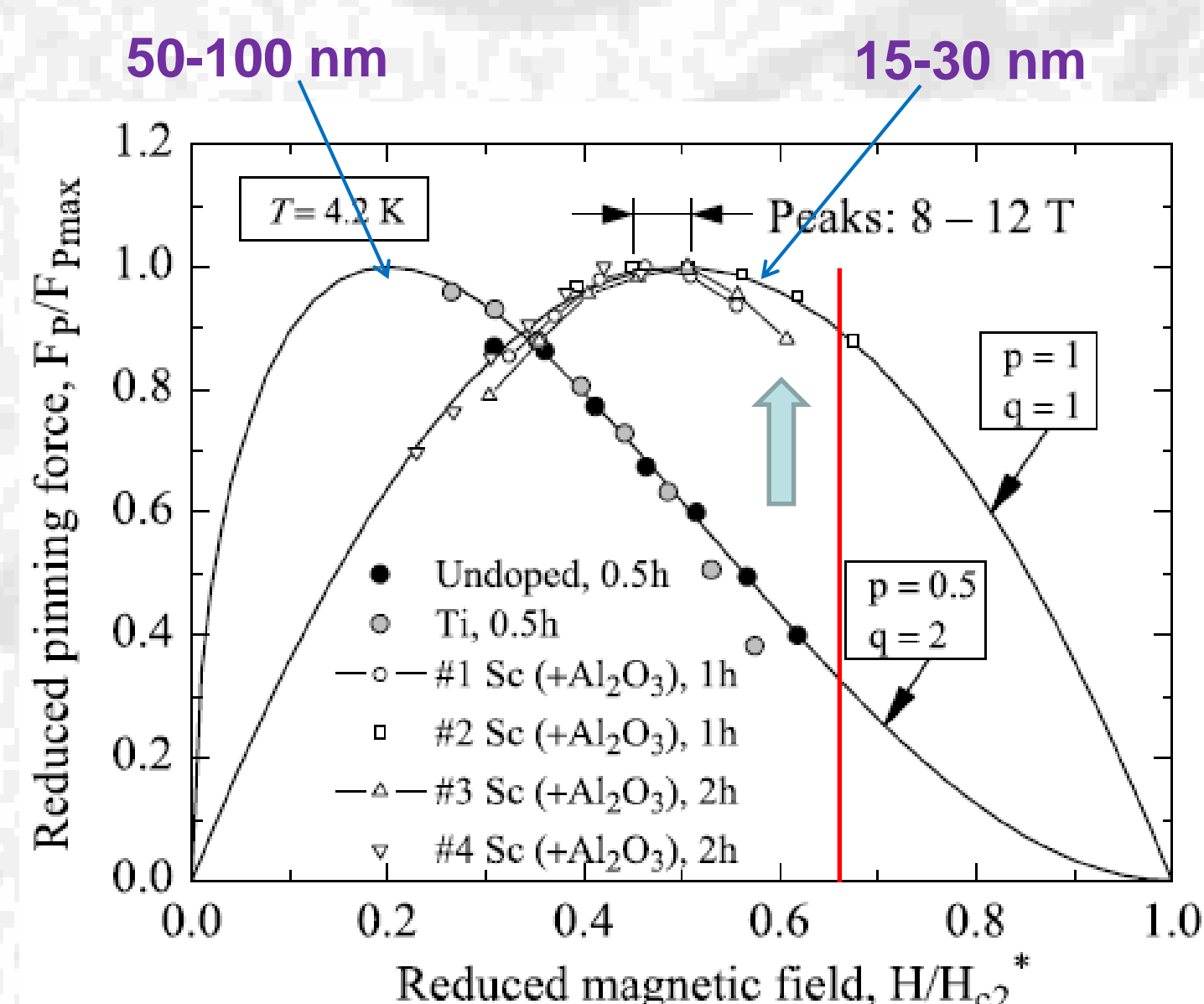
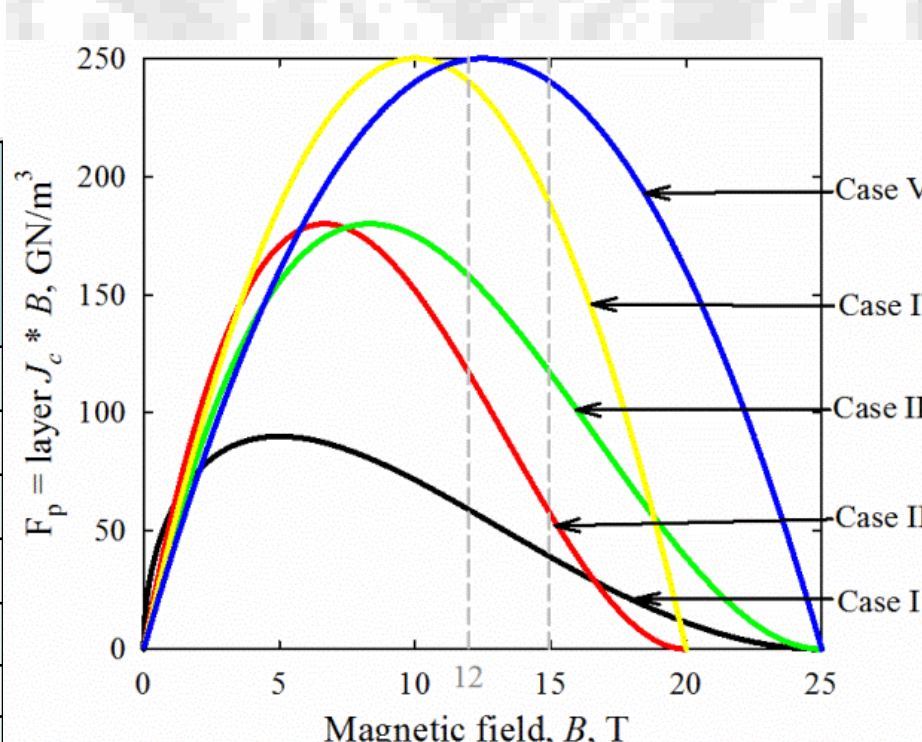
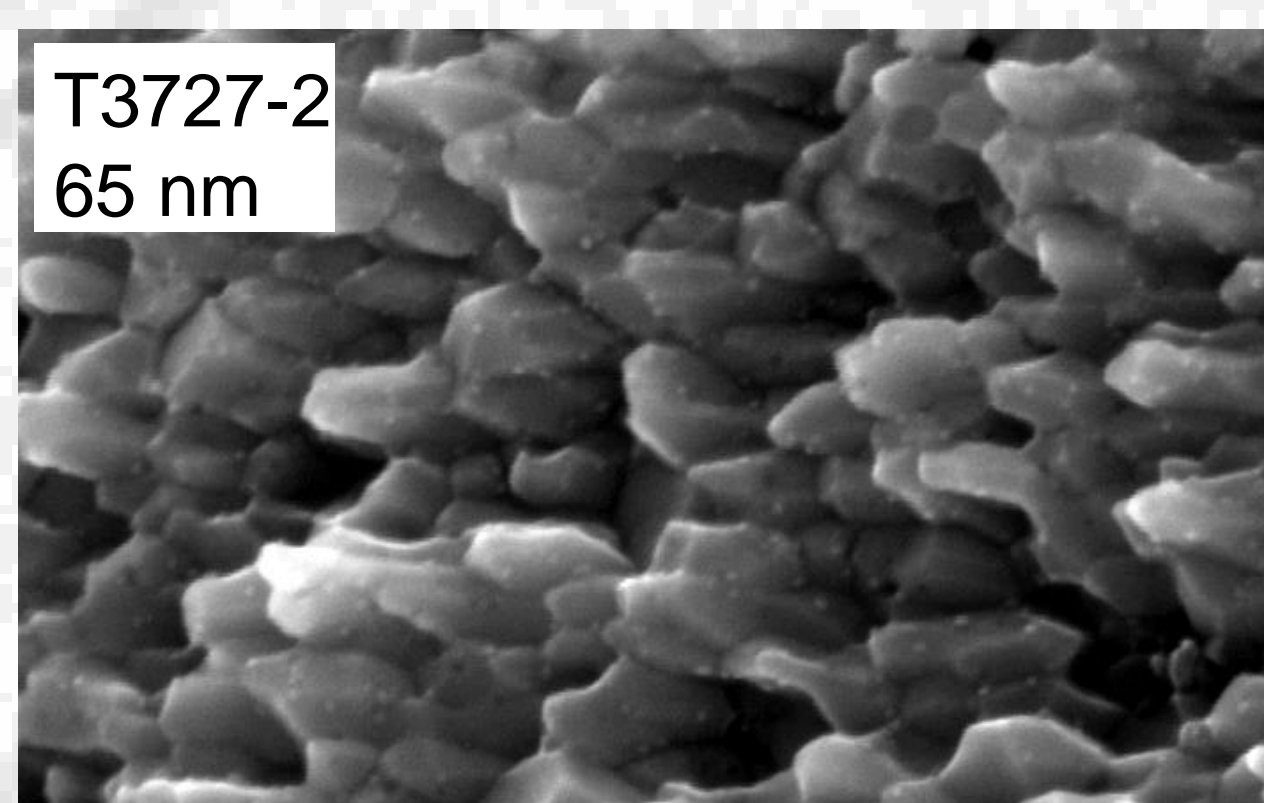


Table 2. "Naïve" look at the theoretical limits of J<sub>c</sub> in Nb<sub>3</sub>Sn

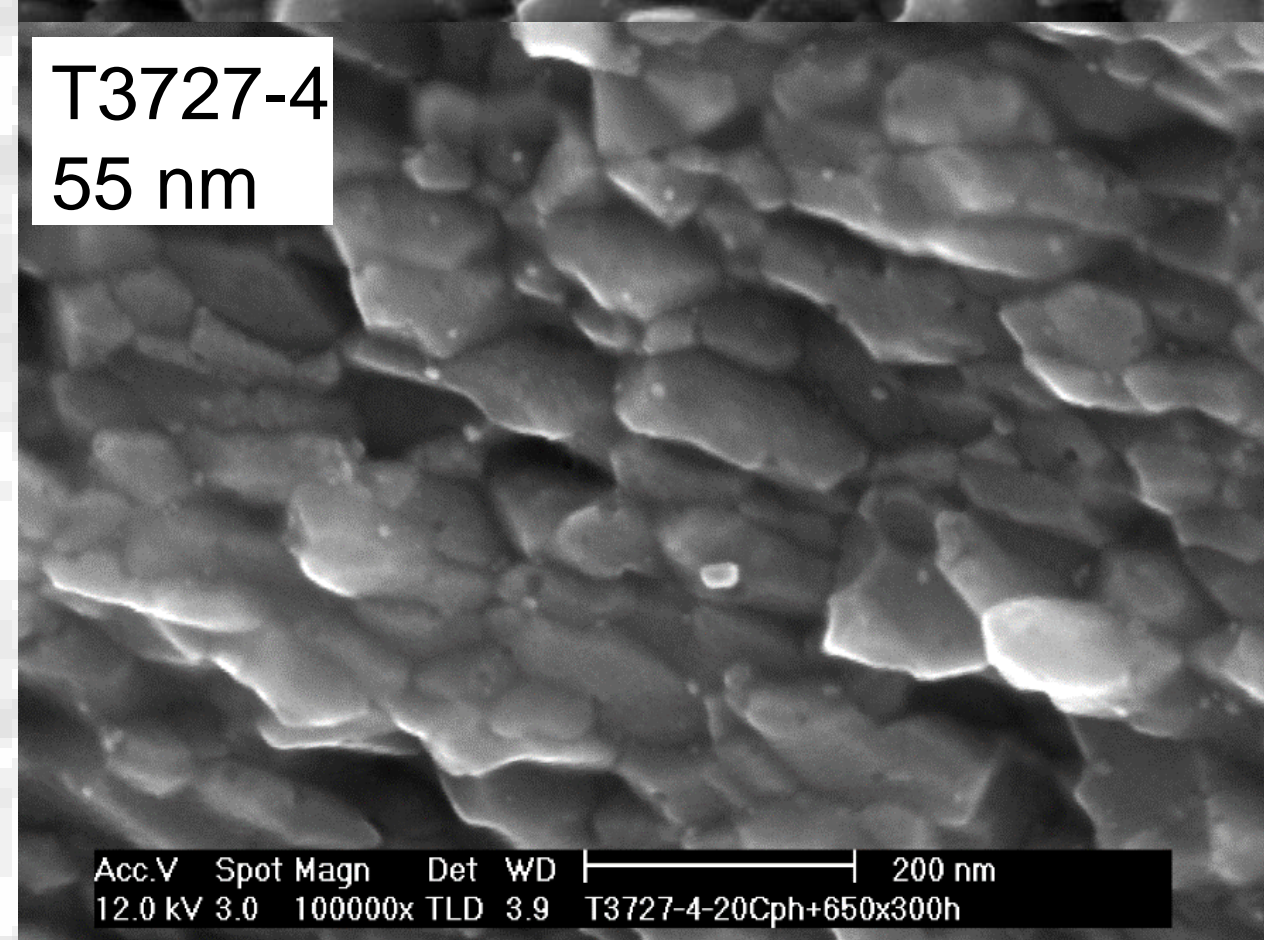
	I. Present state-of-the-art RRP strands	II. The wire with SnO <sub>2</sub> - 625 C / 800h	III. Only improve B <sub>irr</sub> to 25 T by Ti doping, etc.	IV. Only refine the grain size to 25 nm	V. Both improve the B <sub>irr</sub> to 25 T and refine the grain size down to 25 nm
Grain size, nm	100 - 120	36	36	25	25
F <sub>p</sub> -B peak	0.2B <sub>irr</sub>	0.34B <sub>irr</sub>	0.34B <sub>irr</sub>	0.5B <sub>irr</sub>	0.5B <sub>irr</sub>
F <sub>p,max</sub> , GN/m <sup>3</sup>	-90	180	180	-250	-250
B <sub>irr</sub> , T	25	20	25	20	25
Layer J <sub>c</sub> , A/mm <sup>2</sup>	5,000	9,600	16,400	20,000	20,800
Non-Cu J <sub>c</sub> , A/mm <sup>2</sup>	3,000	5,760	9,840	12,000	12,480
Engineering J <sub>c</sub> , A/mm <sup>2</sup>	1,600	3,050	5,200	6,360	6,600
I <sub>c</sub> , A	800	1,530	2,620	3,200	3,320
Layer J <sub>c</sub> , A/mm <sup>2</sup>	2,700	3,800	7,800	12,500	16,000
Non-Cu J <sub>c</sub> , A/mm <sup>2</sup>	1,600	2,280	4,680	7,500	9,600
Engineering J <sub>c</sub> , A/mm <sup>2</sup>	850	1,210	2,480	4,000	5,100
I <sub>c</sub> , A	430	610	1,250	2,000	2,560



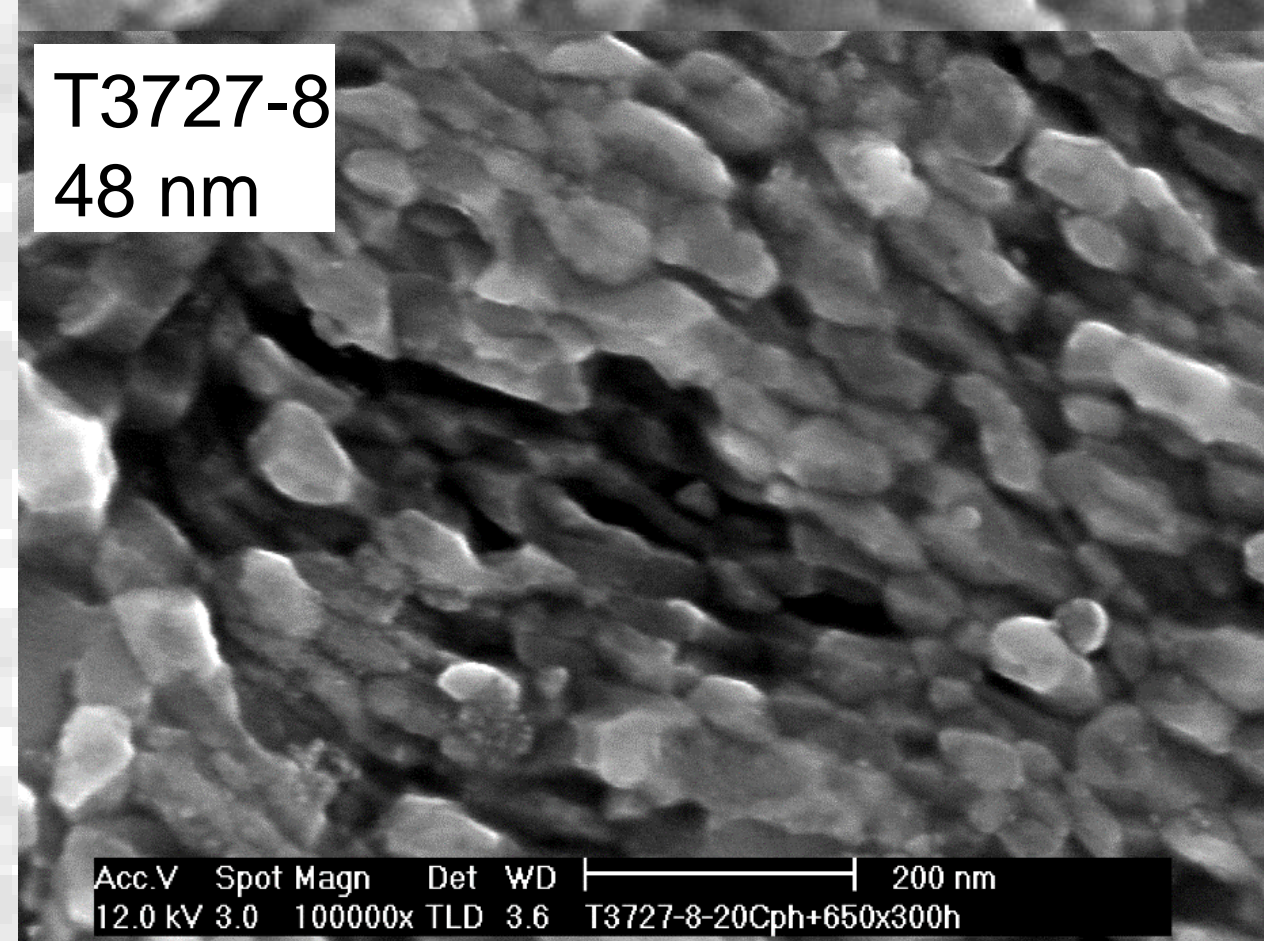
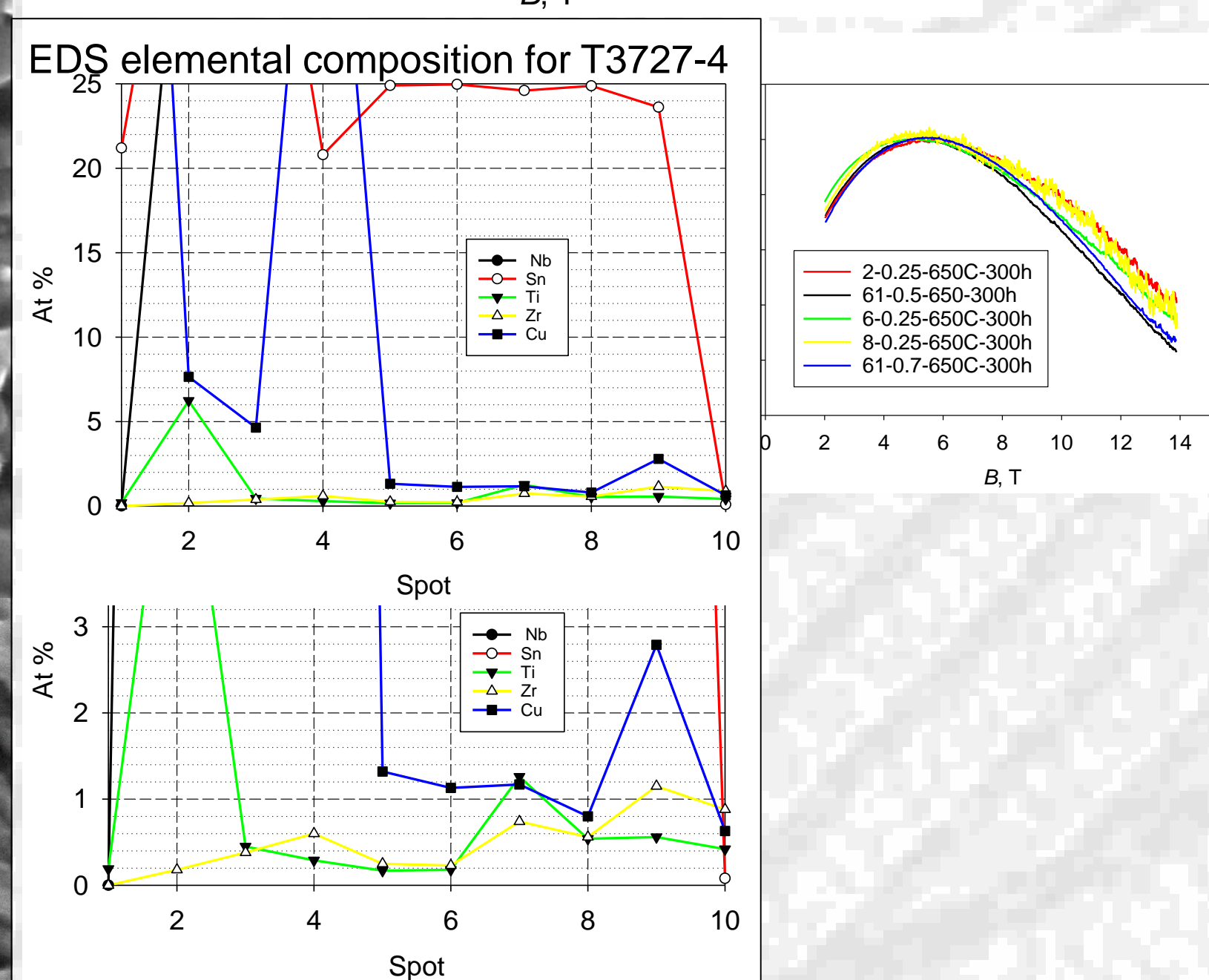
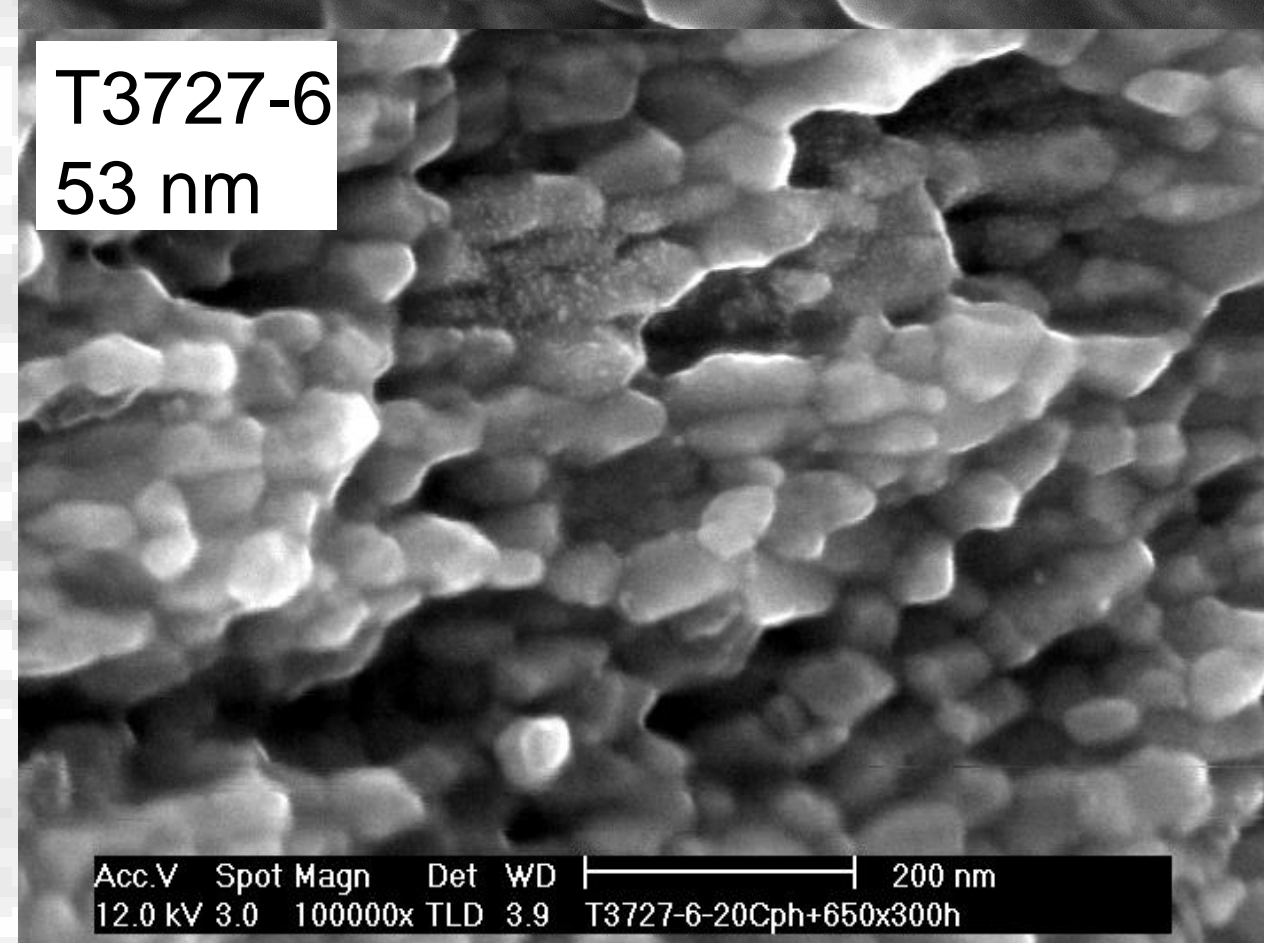
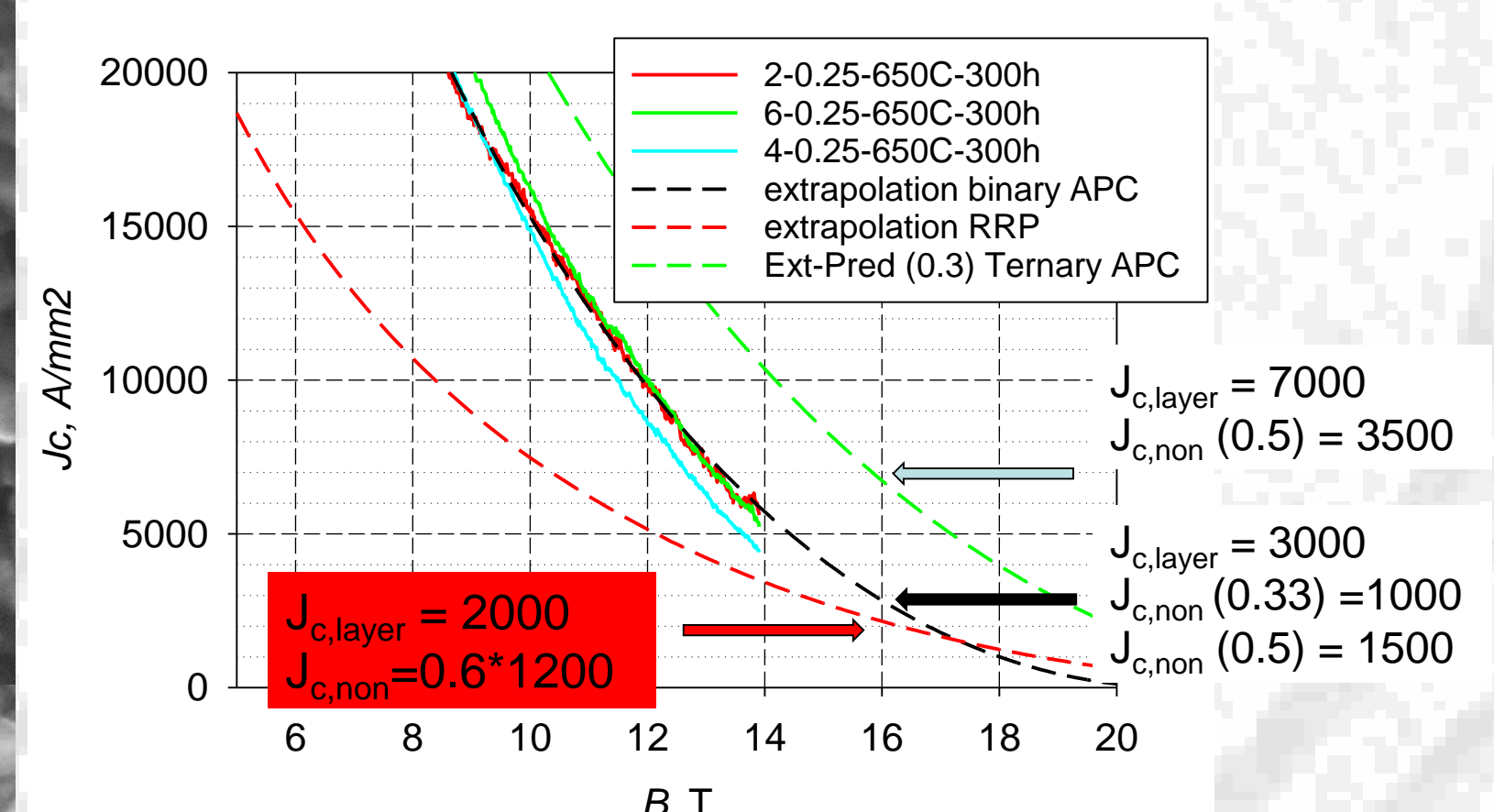
Note: Assumes in all five cases: same Nb<sub>3</sub>Sn area fraction with state of the art RRP strands, 60% Nb<sub>3</sub>Sn area fraction in subelement, non-Cu fraction of 0.53, and wire diameter of 0.8 mm.



Sample Number	CuO content (mg, ±0.1)	Heat treatment
1	1.6	20 C/h + 700Cx100h
2	1.6	20 C/h + 650Cx300h
3	2.6	20 C/h + 700Cx100h
4	2.3	20 C/h + 650Cx300h
5	5.1	20 C/h + 700Cx100h
6	4.2	20 C/h + 650Cx300h
7	9.0	20 C/h + 700Cx100h
8	9.1	20 C/h + 650Cx300h
9	12.1	20 C/h + 700Cx100h
10	11.9	20 C/h + 650Cx300h
11	17.4	20 C/h + 700Cx100h
12	17.5	20 C/h + 650Cx300h
13	31.0	20 C/h + 700Cx100h
14	30.4	20 C/h + 650Cx300h



Sample	Grain size (nm)	Ave Ti %	Bc2 (T)	bmax	bmax/bc2
2	65	1.9	22.6	5.6	0.247345
4	55	1.6	20.3	5.5	0.247345
6	53	1.1	21.3	5	0.234858
8	48	0.25	21.7	5.25	0.242308



## Conclusions

- We have demonstrated grain refinement by a factor of 3 and a doubling of 12 T J<sub>c</sub> in monofilaments
- Internal oxidation can be used in many Nb<sub>3</sub>Sn strand types, including Tube (demonstrated) PIT (proposed), RRP/RIT (proposed) etc.
- Ternary strands under development: Possible to inject Ti into internally oxidized Nb<sub>3</sub>Sn layers
- Sn contents remain high with Ti additions, but Bc2 increase not yet seen – may need to add more Ti
- Multifilamentary strands have been demonstrated with refined grains and enhanced J<sub>c</sub> values.
- New designs which have push non-Cu fraction to above 50% and reaction fraction to above 30% are demonstrated (measurements underway) These need (1) To be optimized, and (2) To be demonstrated for a ternary alloy with the ternary alloy Bc2
- This route is very promising for future Nb<sub>3</sub>Sn development

## References

- [1] Xu, X., Sumption, M. and Peng, X. (2015). Internally Oxidized Nb<sub>3</sub>Sn Strands with Fine Grain Size and High Critical Current Density. *Advanced Materials*, 27(8), pp.1346-1350.
- [2] Xu, X., Sumption, M., Peng, X. and Collings, E. (2014). Refinement of Nb<sub>3</sub>Sn grain size by the generation of ZrO<sub>2</sub> precipitates in Nb<sub>3</sub>Sn wires. *Applied Physics Letters*, 104(8), p.082602.

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